

FEATURES

- Green-mode PWM to support "Blue Angel" Norm
- Low start up current 30uA
- Low operation current 3mA
- Leading-edge blanking
- Built-in synchronized slope compensation Constant output power limit for universal AC input
- Current mode operation
- Cycle-by-cycle current limiting
- Under voltage lockout (UVLO)
- Programmable PWM frequency
- GATE output maximum voltage clamped at 18V
- Totem pole output includes soft driving for better EMI
- Build-in limited-power-control to meet safety requirement
- Programmable over-temperature protection
- Few external components & low cost solution

APPLICATIONS

General-purpose switching mode power supplies and flyback power converters, and

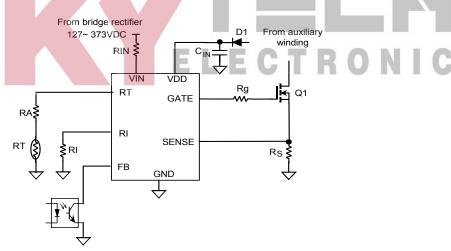
- Power Adapter
- Open-frame SMPS
- Battery Charger Adapter

DESCRIPTION

This highly integrated PWM controllers, SG6841 series, provides several features to enhance the performance of low power flyback converters. To minimize standby power consumption, the proprietary green-mode function provides off-time modulation to linearly decrease the switching frequency under light-load conditions. This green-mode function assists the power supply to easily meet the power conservation requirement. Due to BiCMOS process, the start-up current and operation current is reduced to 30uA and 3mA, respectively, to improve power conversion efficiency. Large start-up resistance can be used for further power saving. Built-in synchronized slope compensation ensures the stability of peak current mode control. A proprietary internal compensation ensures constant output power limit for universal AC input voltage from 90VAC to 264VAC.

SG6841 provides many protection functions. Pulse by pulse current limit ensures a constant output current under short circuit. If a short circuit failure or over load happens, the SG6841 will shut off after a continuous high voltage detection on FB pin. The gate output is clamped at 18V to protect the power MOS from over voltage damage. An external NTC thermistor can be applied to sense the ambient temperature for over-temperature protection. The SG6841 series are available in 8-pin DIP and SO packages.

TYPICAL APPLICATION

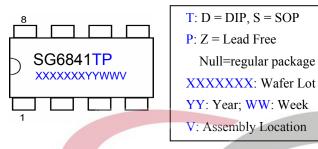


- 1 -

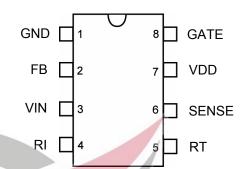
©System General Corp. Version 2.1 (IRO33.0001.B5) www.sg.com.tw Jun.15,2006



MARKING DIAGRAMS



PIN CONFIGURATION



ORDERING INFORMATION

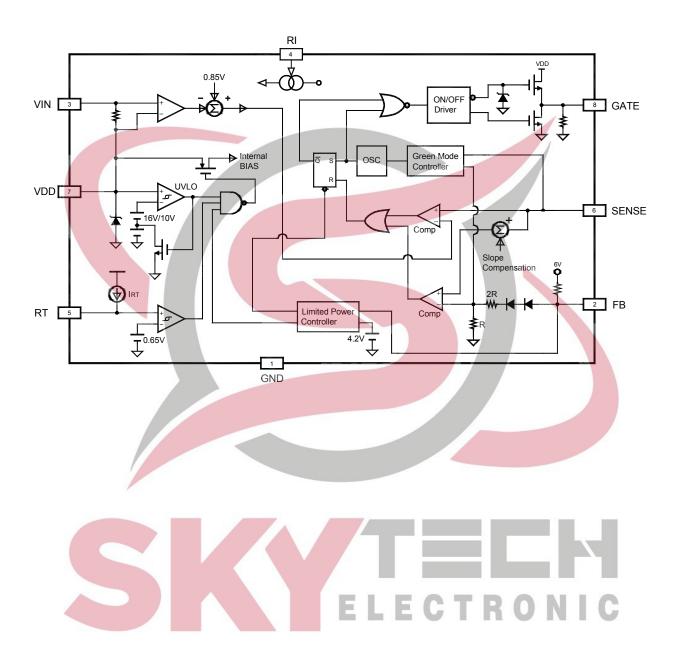
Part Number	Package
SG6841S	8-Pin SOP
SG6841D	8-Pin DIP
SG6841SZ	8-Pin SOP(Lead Free)
SG6841DZ	8-Pin DIP(Lead Free)

PIN DESCRIPTIONS

Pin No.	Symbol	Function	Description
1	GND	Ground	Ground.
2	FB	Feedback	The signal from external compensation circuit is feed into this pin. The PWM duty cycle is determined by this FB pin and current sense signal from Pin 6.
3	VIN	Start-Up	This pin is pulled high to the rectified line input through a resistor for start-up. Since the start-up current requirement for SG6841 is very small, a large start-up resistance can be used to minimize power loss. Under normal operation, this pin is also used to detect line voltage to compensate for constant output power limit for universal AC input.
4	Ri	Reference Setting	A resistor from RI pin to ground will generate a constant current source forSG6841. This current is used to charge an internal capacitor and hence the switching frequency are determined. Increasing the resistance will decrease the current source and reduce the switching frequency. A $26k\Omega$ resistor R _i creates a $50uA$ constant current I _i and generates $65kHz$ switching frequency.
5	RT	Temp <mark>erature</mark> Protection	For over-temperature protection. An external NTC thermistor is connected from this pin to ground. The impedance of the NTC will decrease under high temperature. Once the voltage on RT pin drops below a fixed limit, the PWM output will be disabled.
6	SENSE	Current Sense	Current sense. The sensed voltage is used for current mode control and pulse-by-pulse current limiting.
7	VDD	Power supply	Power Supply.
8	GATE	Driver Output	The totem-pole output driver for the power MOSFET. A soft driving waveform is implemented to improve EMI.



BLOCK DIAGRAM





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
.,	DC Supply Voltage	30	V
V_{DD}	Zener clamp	32	V
	Zener current	10	mA
I _{оит}	Gate Output Current	500	mA
V _{FB}	Input Voltage to FB Pin	-0.3 to 7V	V
V _{Sense}	Input Voltage to SENSE Pin	-0.3 to 7V	V
V_{RT}	Input Voltage to RT Pin	-0.3 to 7V	V
V_{RI}	Input Voltage to Ri Pin	-0.3 to 7V	V
P_D	Power Dissipation	1	W
7	Thermal Resistance Junction-air		
R⊖ j-a	DIP	82.5	°C /W
	SOP	141	
Tυ	Operating Junction Temperature	150	°C
T _A	Operating Ambient Temperature	-30 to 85	°C
Tstg	Storage Temperature Range	-55 to +150	°C
TL	Lead Temperature (Wave soldering or IR, 10 seconds)	260	°C
	ESD Capability, HBM model	3.0	KV
	ESD Capability, Machine model	250	V

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage	<20	V
T _A	Operating Ambient Temperature	-20 to +85	℃
R _I	Current source Setting	26	ΚΩ

ELECTRICAL CHARACTERISTICS

Feedback Input Section

Symbol	Parameter	Test Condition	Min	Тур.	Max.	Unit
A _V	Input-voltage to current-sense attenuation		1/3.25	1/3	1/2.75	V/V
Z _{FB}	Input impedance		2	4.5	8	ΚΩ
I _{FB}	Bias current				2	mA
V_{OZ}	Input voltage for zero duty cycle				1.2	V



Current Sense Section

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Z _{cs}	Input impedance		8	12	16	ΚΩ
T_PD	Delay to Output			150	200	ns
V_{TH}	Threshold voltage for current limit	$I_{VIN} = 0 uA$	0.8	0.85	0.9	V
ΔV _{TH} @ Ι _{VIN}	The change of threshold voltage versus the input current of the Vin	I _{VIN} = 220 uA	-0.09	-0.15	-0.21	V
V _{SENSE0}	Threshold voltage for I _{VIN} = 80uA	$I_{VIN} = 80 \text{ uA}$	0.73	0.81	0.89	V
Tdelay-lps	The delay time of limited-power-control	R _i =26KOhms		31		ms

Oscillator Section

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Fosc	Frequency in nominal mode	R _I =26KOhms	60	65	70	KHz
Fosc-green	Frequency in green mode	R _I =26KOhms		10	16	KHz
V_G	End of green mode voltage at FB pin			1.4		V
V_N	Beginning of frequency reducing at FB pin			2.1		V
S_G	Slope for green mode modulation	R _i =26KOhms	50	80	120	Hz/mV
F_{DV}	Frequency variation versus V _{DD} deviation	V _{DD} =10 to 20V			5	%
F _{DT}	Frequency variation versus Temp. deviation	T _A =-30 to 85 °C			5	%

PWM Section

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
DC (MAX)	Maximum Duty Cycle		75	80	90	%
DC (MIN)	Minimum Duty Cycle		-	-	0	%
Bnk	Leading edge blanking time		200	270	350	ns

Output Section

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
V _{OL}	Output Voltage Low	V_{DD} = 12V, lo = 150mA	TR		1.5	V
V_{OH}	Output Voltage High	V_{DD} = 12V, Io = 50mA	8V			V
tr	Rising Time	V _{DD} =13V, CL=1nF	150	250	350	ns
tf	Falling Time	V _{DD} =13V, CL=1nF	30	50	90	ns

Under-voltage Lockout Section

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
$V_{TH(ON)}$	Start Threshold Voltage		15	16	17	V
$V_{DD(min)}$	Min. Operating Voltage		9	10	11	V

©System General Corp. Version 2.1 (IRO33.0001.B5) - 5 -



Over-Temperature Protection Section

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
I _{RT}	Output current of pin RT	R _i =26KOhms	92	100	108	uA
$V_{\text{OTP,STOP}}$	Threshold voltage for over-temperature protection.		0.585	0.62	0.655	V
	Turn-off point. Duty cycle is reduced to 0%.					
$V_{OTP,START}$	Threshold voltage for over-temperature protection.			0.65		V
	Starting point. Duty cycle starts to decrease.					

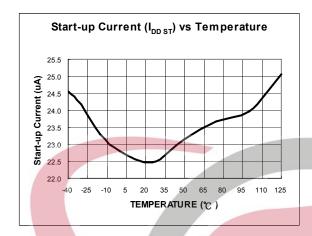
Total Standby Current Section

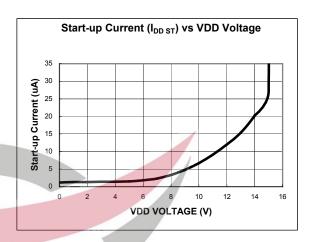
Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
I _{DD ST}	Start-up Current	VDD=14.5V		30	40	uA
I _{DD OP}	Operating Supply Current	FB=SENSE=0V GATE=1000pF		3	5	mA
		VDD=15.5V				

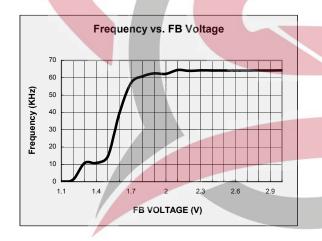


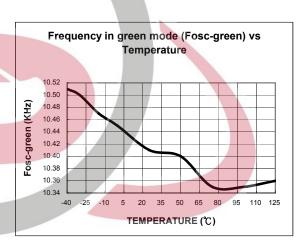


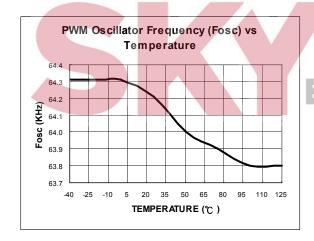
TYPICAL CHARACTERISTICS

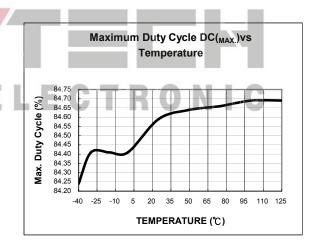




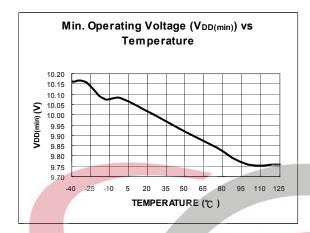


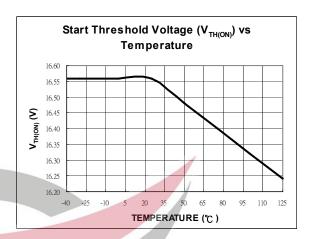


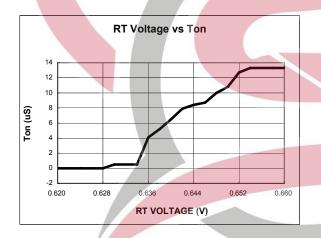


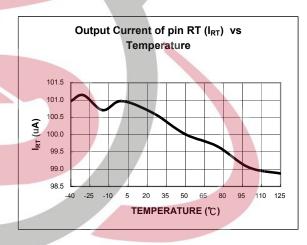


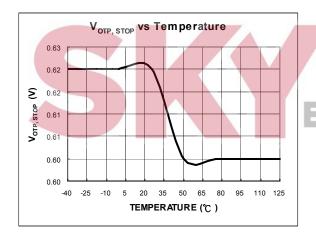


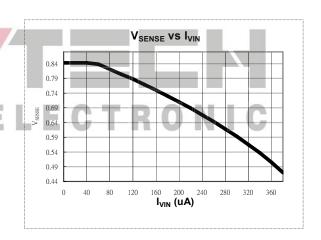














OPERATION DESCRIPTION Start-up current

Typical start-up current is only 30uA so that a high resistance, and low-wattage, start-up resistor can be used to minimize power loss. For an AC/DC adapter with universal input range, a 1.5 M Ω , 0.25W, start-up resistor and a 10uF/25V VDD hold-up capacitor are enough for this application.

Operating current

Operating current has been reduced to 3mA. The low operating current enables a better efficiency and reduces the requirement of VDD hold-up capacitance.

Green Mode Operation

The patented green-mode function provides an off-time modulation to reduce the switching frequency in the light load and no load conditions. The on time is limited for better abnormal or brownout protection. V_{FB} , which is derived from the voltage feedback loop, is taken as the reference. Once V_{FB} is lower than the threshold voltage, switching frequency will be linearly decreased to the minimum green mode frequency around 10kHz ($R_i = 26k\Omega$).

Oscillator Operation

A resistor from RI pin to ground will generate a constant current source for SG6841. This current is used to charge an internal capacitor and hence the internal clock and switching frequency are determined. Increase the resistance will decrease the current source and reduce the switching frequency. A $26k\Omega$ resistor R_i creates a 50uA constant current I_i and generates 65kHz switching frequency. The relation between Ri and switching freauency is:

$$\mathbf{f}_{PWM} = \frac{1690}{R_{I} (k\Omega)} (kHz)$$
(1)

The range of the PWM oscillation frequency is designed as $50 \text{kHz} \sim 90 \text{kHz}$.

Current sensing and PWM current limiting

Peak current mode control is utilized in SG6841 to regulate output voltage and provide pulse by pulse current limiting. The switch current is detected by a sense resistor into the sense pin of SG6841. The PWM duty cycle is determined by this current sense signal and V_{FB} , the feedback voltage. When the voltage on sense pin reaches $V_{COMP} = (V_{FB}-1.0)/3$, a switch cycle will be terminated immediately. V_{COMP} is internally clamped to a variable voltage around 0.85v for output power limit.

Leading Edge Blanking

Each time when the power MOSFET is switched on, a turn-on spike will inevitably occur on the sense-resistor. To avoid premature termination of the switching pulse, a 270 nsec leading-edge blanking time is built in. Conventional RC filtering can therefore be omitted. During this blanking period, the current-limit comparator is disabled and it cannot switch off the gate driver.

Under-voltage lockout (UVLO)

The turn-on and turn-off threshold of SG6841 are fixed internally at 16V/10V. During start-up, the hold-up capacitor must be charged to 16V through the start-up resistor so that SG6841 will be enabled. The hold-up capacitor will continue to supply V_{DD} before the energy can be delivered from auxiliary winding of the main transformer. V_{DD} must not drop below 10V during this start-up process. This UVLO hysteresis window insures that hold-up capacitor is adequate to supply V_{DD} during start-up.

Gate Output / Soft Driving

The SG6841 BiCMOS output stage is a fast totem pole gate driver. Cross conduction has been avoided to minimize heat dissipation, increases efficiency and enhances reliability. The output driver is clamped by an internal 18V Zener diode in order to protect power MOSFET transistors against undesirable gate over voltage. A soft driving waveform is implemented to minimize EMI.



Built-in Slope Compensation

The sensed voltage across the current sense resistor is used for current mode control and pulse-by-pulse current limiting. Built-in slope compensation will improve stability or prevent sub-harmonic oscillation of peak current mode control. SG6841 inserts a synchronized positive-going ramp at every switching cycle. Vs-comp = 0.33V.

Constant Output Power Limit

When the SENSE voltage, across the sense resistor Rs, reaches the threshold voltage, around 1.0V, the output GATE drive will be turned off after a small propagation delay t_D. This propagation delay will introduce an additional current proportional to t_D*Vin/Lp. Since the propagation delay is nearly constant regardless of the input line voltage V_{IN}. Higher input line voltage will result in a larger additional current and hence the output power limit is also higher than that under low input line voltage. To compensate this variation for wide AC input range, the threshold voltage is adjusted by the V_{IN} current. Since VIN pin is connected to the rectified input line voltage through the start-up resistor, a higher line voltage will generate higher V_{IN} current into the VIN pin. The threshold voltage is decreased if the V_{IN} current is increased. Smaller threshold voltage, forces the output GATE drive to terminate earlier, thus reduce the total PWM turn-on time and make the output power equal to that of low line input. This proprietary internal compensation ensures a constant output power limit for wide AC input voltage from 90VAC to 264VAC.

Thermal Protection

An NTC thermistor Rntc in series with a resistor Ra can be connected from pin RT to ground. A constant current I_{RT} is output from pin RT. The voltage on RT pin can be expressed as $V_{RT} = I_{RT} \times (Rntc + Ra)$ in which $I_{RT} = 2 \times (1.3 \text{V} / \text{Ri})$.

At high ambient temperature, Rntc will be smaller such that V_{RT} will decrease. When V_{RT} is less than 0.65V ($V_{OTP,START}$), the PWM duty cycle will be decreased to lower the internal temperature of power supply. If the over heating situation still exists such that V_{RT} decreases further to 0.62V ($V_{OTP,STOP}$), the PWM will be completely turned off.

Limited Power Control

Every time when the output of power supply is shorted or over loaded, the FB voltage will increase. If the FB voltage is higher than a designed threshold, 4.2V, for longer than 31msec, the PWM output will then be turned off eternally. $V_{\rm DD}$, the supply voltage for SG6841, will decrease due to the supply current for SG6841. When $V_{\rm DD}$ is lower than the turn-off threshold such as 10V, SG6841 will be totally shut down. Due to the start up resistor, $V_{\rm DD}$ will be charged up to the turn-on threshold voltage 16V until SG6841 is enabled again. If the over loading condition still exists, above protection will take place repeatedly. This will prevent the power supply from being overheated under over loading condition.

Noise immunity

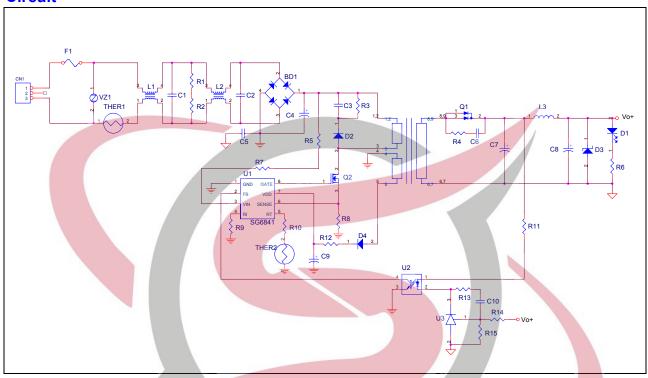
Noise on the current sense or control signal may cause significant pulse width jitter, particularly in the continuous conduction mode. Slope compensation helps alleviate this problem. Good placement and layout practices should be followed. Avoiding long PCB traces and component leads, locating compensation and filter components near to the SG6841, and increasing the power MOS gate resistance will always help.

ELECTRONIC



REFERENCE CIRCUIT

Circuit

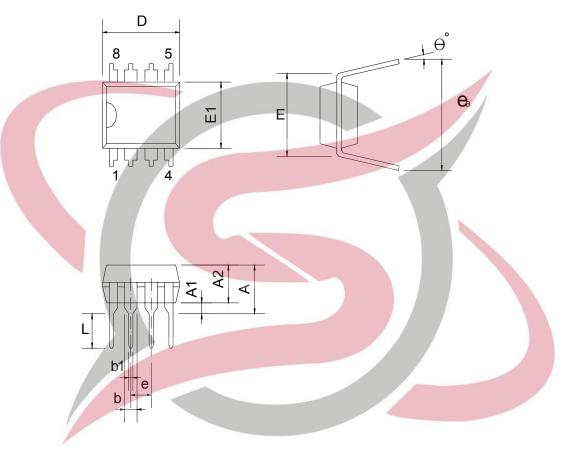


BOM

Reference	Component	Reference	Component	
BD1	BD 4A/600V	R1,R2	R 1Mohm 1/4W	
C1	XC 0.1uF/275V	R3	R 100Kohm 1/2W	
C2	XC 0.22uF/275V	R4	R 47ohm 1/4W	
C3	CC 0.01uF/500V	R5,R7	R 750Kohm 1/4W	
C4	EC 120u/400V	R6	R 20Kohm 1/8W	
C5	YC 222p/Y1	R8	R 0.3ohm 2W	
C6	CC 1000pF/100V	R9	R 33Kohm 1/8W	
C7	CC 1000pF/50V	R9	R 20Kohm 1/8W 1%	
C8	EC 1000uF/35V	R11	R 220ohm 1/8W	
C9	EC 220uF/35V	R12	R 4.7ohm 1/8W	
D1	LED	R13	R 6.8Kohm 1/8W	
D2	Diode FR157	R14	R 154Kohm 1/8W	
D3	ZD 18V	R15	R 390Kohm 1/8W	
D4	Diode FR102	THER1	Thermistor SCK054	
F1	FUSE 4A/250V		Transformer	
L1	900uH	U1	IC SG6841	
L2	15mH	U2	IC PC817	
Q1	Diode 20A100V	U3	IC TL431	
Q2	MOS 7A/600V	VZ1	VZ 9G	



PACKAGE INFORMATION 8 PINS- DIP (D)

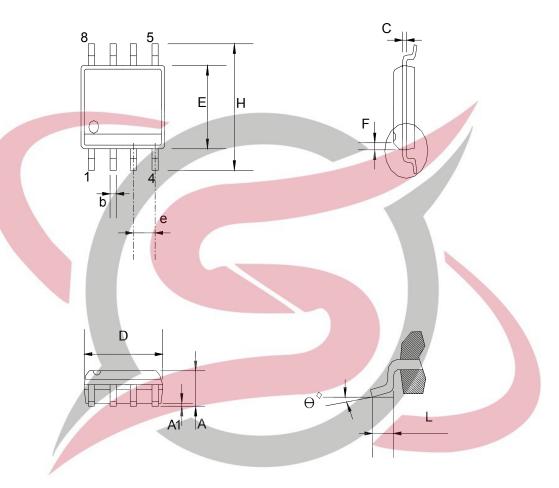


Dimension

					.7:	
Symbol	Millimeter			Inch		
	Min.	Typ.	Max.	Min.	Тур.	Max.
Α			5.334			0.210
A1	0.381			0.015	Name and the same of	
A2	3.175	3.302	3.429	0.125	0.130	0.135
b		1.524			0.060	0.14
b1		0.457			0.018	
D	9.017	9.271	10.160	0.355	0.365	0.400
Е		7.620			0.300	
E1	6.223	6.350	6.477	0.245	0.250	0.255
е		2.540			0.100	
L	2.921	3.302	3.810	0.115	0.130	0.150
ев	8.509	9.017	9.525	0.335	0.355	0.375
θ °	0°	7°	15°	0°	7°	15°



8 PINS-SOP(S)



Dimension

Symbol -	Millimeter			Inch		
	Min.	Тур.	Max.	Min.	Тур.	Max.
A	1.346		1.752	0.053	TR	0.069
A1	0.101		0.254	0.004		0.010
b		0.406			0.016	
С		0.203			0.008	
D	4.648		4.978	0.183		0.196
E	0.381		3.987	0.150		0.157
е		1.270			0.050	
F		0.381X45°			0.015X45°	
Н	5.791		6.197	0.228		0.244
L	0.406	•	1.270	0.016		0.050
θ °	0°		8°	0°		8°



LIFE SUPPORT

System General's products are not designed to be used as components in devices intended to support or sustain human life. Use of System General's products in components intended for surgical implant into the body, or other applications in which failure of the System General's products could create a situation where personal death or injury may occur, is not authorized without the express written approval of System General's Chief Executive Officer. System General will not be held liable for any damages or claims resulting from the use of its products in medical applications.

MILITARY

System General's products are not designed for use in military applications. Use of System General's products in military applications is not authorized without the express written approval of System General's Chief Executive Officer. System General will not be held liable for any damages or claims resulting from the use of its products in military applications.

RIGHT TO MAKE CHANGES

System General reserves the right to change this document and/or this product without notice. Customers are advised to consult their System General sales representative before ordering.

©System General Corp. Version 2.1 (IRO33.0001.B5) - 14 -

www.sg.com.tw Jun.15,2006